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Express Mail No. ER452509568US IFW
Attorney Docket No.: AM-8893

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Ki-Ho Baik et al.

FILED: April 2, 2004

SERIAL NO.: 10/817,140

FOR: METHOD OF IMPROVING THE UNIFORMITY

OF A PATTERNED PHOTORESIST ON A MASK

§ Attorney Docket No.:

**EXAMINER:** Unknown

§ GROUP ART UNIT: Unknown

AM-8893

Date: June 23, 2004

## INFORMATION DISCLOSURE STATEMENT TRANSMITTAL LETTER

Hon. Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

Applicants are submitting the subject Information Disclosure Statement under 37 CFR § 1.97(b)(1). This Information Disclosure Statement is being submitted within three (3) months of the filing date of the subject application.



# **CERTIFICATE OF MAILING UNDER 37 CFR § 1.10**

I hereby certify that this paper is being deposited with the U.S. Postal Service on the date shown below with sufficient postage as U.S. EXPRESS MAIL NO. ER452509568US in an envelope addressed to: Mail Stop DD, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Date: June 23, 2004

Shirley L. Church, Reg. No. 31,858

Applicants do not believe that any fee is due in connection with the filing of this Information Disclosure Statement under 37 CFR § 1.97(b)(1). However, in the event that any additional fee is due, the Commissioner is hereby authorized to charge Deposit Account No. 50-1512 of Shirley L. Church, Sunnyvale, California, in the amount of such fee.

This transmittal letter is submitted in duplicate for accounting purposes.

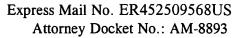
Respectfully submitted,

Shirley L.Church

Registration No. 31,858

Attorney for Applicants

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Applied Materials, Inc.
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Santa Clara, California 95052





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# INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)(1)

Hon. Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

In accordance with 37 CFR § 1.97(b)(1), applicants hereby request consideration of this Information Disclosure Statement. This Information Disclosure Statement is being submitted within three (3) months of the filing date of the subject application. Applicants are providing herewith a copy of each document cited on the attached Form PTO-1449.

# **CERTIFICATE OF MAILING UNDER 37 CFR § 1.10**

I hereby certify that this paper is being deposited with the U.S. Postal Service on the date shown below with sufficient postage as U.S. EXPRESS MAIL NO. ER452509568US in an envelope addressed to: Mail Stop DD, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Date: June 23, 2004 Surley S. Church

Shirley L. Church, Reg. No. 31,858

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The submission of this Information Disclosure Statement and Form PTO-1449 is not an admission that the art cited is "prior art" with respect to the present invention, nor is it a representation that no better art exists. Applicants hereby reserve the right to swear behind or otherwise disprove any alleged "prior" nature of any art cited should the facts support and the situation warrant such an action.

If the Examiner has any questions, s/he is respectfully requested to contact the undersigned attorney at the telephone number set forth below.

Respectfully submitted,

Shirley L. Church
Shirley L. Church

Registration No. 31,858 Attorney for Applicants

(650) 473-9700

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P.O. Box 450-A
Santa Clara, California 95052

FORM PTO-1449 (Equivalent) U.S. Department of Commerce Patent and Trademark Office

U.S. Application Serial No. 10/817,140

Atty. Docket No. AM-8893

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use several sheets if necessary)

<u>Ki-Ho Baik et al.</u> Applicants

April 2, 2004 Filing Date

<u>Unknown</u> Group

U. S	. P	AT	ENT	DOC	CUMENTS	3
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Examiner	Document	Issue				Filing Date
<u>Initial</u>	Number	<u>Date</u>	Name Name	<u>Class</u>	<u>Subclass</u>	If Appropriate
	4,102,683	07/25/78	DiPiazza	96	38.4	
	5,554,485	09/10/96	Dichiara et al.	430	271.1	
	5,723,237	03/03/98	Kobayashi et al.	430	30	
	5,879,853	03/09/99	Azuma	430	166	
	5,879,863	03/09/99	Azuma et al.	430	322	
	5,935,768	08/10/99	Biche et al.	430	401	
	6,048,672	04/11/00	Cameron et al.	430	327	
	6,703,169	03/09/04	Fuller et al.	430	5	

#### U. S. PATENT APPLICATION DOCUMENTS

Examiner Initial	Document Number	Publication Date	Name	Class	Subclass	Filing Date
	2002/0012876 A1	01/31/02	Angelopolous et al.	430	271.1	08/17/01
	2002/0182514 A1	12/05/02	Montgomery et al.	430	5	05/03/01

Examiner

Date Considered

Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

# FOREIGN PATENT DOCUMENTS

Examiner Initial	Document Number	Publication <u>Date</u>	n Name	Class	Subclass	Translation (If Appropriate)		
	EP 0987600	03/22/00	Adams et al.	G03F	7/09			
	EP 0989460	03/29/00	Shimomura et al.	G03F	7/004			
	JP 10048831		Sony Corp.	G03F	007/11	Abstract		
	ОТНЕ	R DOCUME	ENTS (Including Author, T	itle, Date, Pert	inent Pages, e	tc.)		
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	P. Buck et al., "Performance of the ALTA® 3500 scanned-laser mask lithography system", Proceedings of the SPIE Conference on Photomask ad X-Ray Mask Technology V, Kawasaki, Japan, SPIE Vol. 3412, pp. 67-78 (April 1998).							
	K. Katoh et al., "Improvement of Post Exposure Delay Stability of Chemically Amplified Positive Resist", <i>Proceedings of the SPIE Symposium on Photomask and X-Ray Mask Technology VI</i> , Yokohama, Japan, SPIE Vol. 3748, pp. 62-68 (Sept 1999).							
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			tion of a General Reaction Exposure", SPIE, Vol. 30			merging Materials with		
Examiner		Date Co	onsidered					

Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.